

**Burr-Brown Products** from Texas Instruments



**OPA703 OPA2703 OPA4703 OPA704 OPA2704 OPA4704** 

SBOS180A - MARCH 2001

# CMOS, Rail-to-Rail, I/O **OPERATIONAL AMPLIFIERS**

## **FEATURES**

- RAIL-TO-RAIL INPUT AND OUTPUT
- WIDE SUPPLY RANGE: Single Supply: 4V to 12V Dual Supplies: ±2 to ±6
- LOW QUIESCENT CURRENT: 160µA
- FULL-SCALE CMRR: 90dB
- LOW OFFSET: 160μV
- HIGH SPEED: OPA703: 1MHz, 0.6V/µs **OPA704: 3MHz, 3V/µs**
- MicroSIZE PACKAGES: SOT23-5, MSOP-8, TSSOP-14
- LOW INPUT BIAS CURRENT: 1pA

## APPLICATIONS

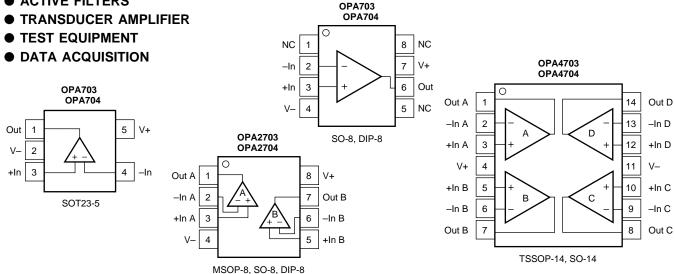
- AUTOMOTIVE APPLICATIONS: Audio, Sensor Applications, Security Systems
- PORTABLE EQUIPMENT
- ACTIVE FILTERS

# DESCRIPTION

The OPA703 and OPA704 series op amps are optimized for applications requiring rail-to-rail input and output swing. Single, dual, and quad versions are offered in a variety of packages. While the quiescent current is less than 200µA per amplifier, the OPA703 still offers excellent dynamic performance (1MHz GBW and 0.6V/µs SR) and unity-gain stability. The OPA704 is optimized for gains of 5 or greater and provides 3MHz GBW and 3V/µs slew rate.

The OPA703 and OPA704 series are fully specified and guaranteed over the supply range of  $\pm 2V$  to  $\pm 6V$ . Input swing extends 300mV beyond the rail and the output swings to within 40mV of the rail.

The single versions (OPA703 and OPA704) are available in the MicroSIZE SOT23-5 and in the standard SO-8 surfacemount, as well as the DIP-8 packages. Dual versions (OPA2703 and OPA2704) are available in the MSOP-8, SO-8, and DIP-8 packages. The quad OPA4703 and OPA4704 are available in the TSSOP-14 and SO-14 packages. All are specified for operation from -40°C to +85°C.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Supply Voltage, V+ to V	13.2V
Signal Input Terminals, Voltage <sup>(2)</sup>	(V–) –0.3V to (V+) +0.3V
Current <sup>(2)</sup>	
Output Short-Circuit <sup>(3)</sup>	Continuous
Operating Temperature	–55°C to +125°C
Storage Temperature	65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

NOTES: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. (2) Input terminals are diode-clamped to the power supply rails. Input signals that can swing more than 0.3V beyond the supply rails should be current-limited to 10mA or less. (3) Short-circuit to ground, one amplifier per package.

## ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **PACKAGE/ORDERING INFORMATION**

PRODUCT	DESCRIPTION	MINIMUM RECOMMENDED GAIN	PACKAGE	PACKAGE DRAWING NUMBER	PACKAGE MARKING	ORDERING NUMBER <sup>(1)</sup>	TRANSPORT MEDIA
OPA703NA	Single, GBW = 1MHz	1	SOT23-5	331	A03	OPA703NA/250	Tape and Reel
"	"	"	"	"	"	OPA703NA/3K	Tape and Reel
OPA703UA	Single, GBW = 1MHz	1	SO-8	182	OPA703UA	OPA703UA	Rails
"	"	"	"	"	"	OPA703UA/2K5	Tape and Reel
OPA703PA	Single, GBW = 1MHz	1	DIP-8	006	OPA703PA	OPA703PA	Rails
OPA2703EA	Dual, GBW = 1MHz	1	MSOP-8	337	B03	OPA2703EA/250	Tape and Reel
"	"	"		"	"	OPA2703EA/2K5	Tape and Reel
OPA2703UA	Dual, GBW = 1MHz	1	SO-8	182	OPA2703UA	OPA2703UA	Rails
"	"	"	"	"	"	OPA2703UA/2K5	Tape and Reel
OPA2703PA	Dual, GBW = 1MHz	1	DIP-8	006	OPA2703PA	OPA2703PA	Rails
OPA4703EA	Quad, GBW = 1MHz	1	TSSOP-14	357	OPA4703EA	OPA4703EA/250	Tape and Reel
"	"	"	"	"	"	OPA4703EA/2K5	Tape and Reel
OPA4703UA	Quad, GBW = 1MHz	1	SO-14	235	OPA4703UA	OPA4703UA	Rails
"	"	"	"	"	"	OPA4703UA/2K5	Tape and Reel
OPA704NA	Single, GBW = 5MHz	5	SOT23-5	331	A04	OPA704NA/250	Tape and Reel
"	"	"	"	"	"	OPA704NA/3K	Tape and Reel
OPA704UA	Single, GBW = 5MHz	5	SO-8	182	OPA704UA	OPA704UA	Tape and Reel
"	"	"	"	"	"	OPA704UA/2K5	Tape and Reel
OPA704PA	Single, GBW = 5MHz	5	DIP-8	006	OPA704PA	OPA704PA	Rails
OPA2704EA	Dual, GBW = 5MHz	5	MSOP-8	337	B04	OPA2703EA/250	Tape and Reel
"	"	"	"	"	"	OPA2703EA/2K5	Tape and Reel
OPA2704UA	Dual, GBW = 5MHz	5	SO-8	182	OPA2704UA	OPA2704UA	Rails
"	"	"	"	"	"	OPA2704UA/2K5	Tape and Reel
OPA2704PA	Dual, GBW = 5MHz	5	DIP-8	006	OPA2704PA	OPA2704PA	Rails
OPA4704EA	Quad, GBW = 5MHz	5	TSSOP-14	357	OPA4704EA	OPA4704EA/250	Tape and Reel
"	"	"	"	"	"	OPA4704EA/2K5	Tape and Reel
OPA4704UA	Quad, GBW = 5MHz	5	SO-14	235	OPA4704UA	OPA4704UA	Rails
"	"	"	"	"	"	OPA4704UA/2K5	Tape and Reel

NOTE: (1) Models with a slash (/) are available only in Tape and Reel in the quantities indicated (e.g., /3K indicates 3000 devices per reel). Ordering 3000 pieces of "OPA703NA/3K" will get a single 3000-piece Tape and Reel.



# OPA703 ELECTRICAL CHARACTERISTICS: $V_s = 4V$ to 12V

### Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+85^{\circ}C$

At T<sub>A</sub> = +25°C, R<sub>L</sub> = 20k $\Omega$  connected to V<sub>S</sub>/2 and V<sub>OUT</sub> = V<sub>S</sub>/2, unless otherwise noted.

		OF	PA703NA, UA, PA2703EA, UA OPA4703EA, L	, PA	
PARAMETER	CONDITION	MIN	ТҮР	MAX	UNITS
OFFSET VOLTAGE           Input Offset Voltage         V           Drift         dVos /           vs Power Supply         PSF           Over Temperature         Channel Separation, dc           f = 1kHz         f			±160 ± <b>4</b> 20 1 98	±750 100 <b>200</b>	μV μ <b>V/°C</b> μV/∨ μ <b>V/ν</b> μV/ν dB
INPUT VOLTAGE RANGE Common-Mode Voltage Range V Common-Mode Rejection Ratio over Temperature over Temperature	$ \begin{array}{c} \sum_{k=1}^{2M} \\ V_{k} = \pm 5V, \ (V-) - 0.3V < V_{CM} < (V+) + 0.3V \\ V_{k} = \pm 5V, \ (V-) < V_{CM} < (V+) \\ V_{k} = \pm 5V, \ (V-) - 0.3V < V_{CM} < (V+) - 2V \\ V_{k} = \pm 5V, \ (V-) < V_{CM} < (V+) - 2V \end{array} $	(V−) − 0.3 70 <b>68</b> 80 <b>74</b>	90 96	(V+) + 0.3	∨ dB dB dB
INPUT BIAS CURRENT Input Bias Current	$V_{\rm S} = \pm 5V, V_{\rm CM} = 0V$		±1	±10	pA
•	$V_{\rm S} = \pm 5 V, V_{\rm CM} = 0 V$		±0.5	±10	pA
INPUT IMPEDANCE Differential Common-Mode			4 • 10 <sup>9</sup>    4 5 • 10 <sup>12</sup>    4		Ω    pF Ω    pF
NOISE Input Voltage Noise, f = 0.1Hz to 10Hz Input Voltage Noise Density, f = 1kHz Current Noise Density, f = 1kHz	$ \begin{array}{c} V_{S}=\pm 5V, \ V_{CM}=0V\\ V_{S}=\pm 5V, \ V_{CM}=0V\\ i_{n} & V_{S}=\pm 5V, \ V_{CM}=0V \end{array} $		6 45 2.5		μVp-p nV/√Hz fA/√Hz
OPEN-LOOP GAIN Open-Loop Voltage Gain	$R_{L} = 100k\Omega, (V-)+0.1V < V_{O} < (V+)-0.1V$ $R_{L} = 20k\Omega, (V-)+0.075V < V_{O} < (V+)-0.075V$	100	120 110		dB dB
over Temperature over Temperature	$ \begin{array}{l} \textbf{R}_{L} = 20k\Omega, \ (V) + 0.075V < V_{O} < (V_{+}) - 0.075V \\ \textbf{R}_{L} = 5k\Omega, \ (V) + 0.15V < V_{O} < (V_{+}) - 0.15V \\ \textbf{R}_{L} = 5k\Omega, \ (V) + 0.15V < V_{O} < (V_{+}) - 0.15V \\ \end{array} $	96 100 96	110		dB dB dB
OUTPUT		30			ub
Voltage Output Swing from Rail over Temperature	$\begin{array}{l} R_{L} = 100 \mathrm{k}\Omega, \ A_{OL} > 80 \mathrm{dB} \\ R_{L} = 20 \mathrm{k}\Omega, \ A_{OL} > 100 \mathrm{dB} \\ \textbf{R}_{L} = 20 \mathrm{k}\Omega, \ \textbf{A}_{OL} > 96 \mathrm{dB} \\ R_{L} = 5 \mathrm{k}\Omega, \ A_{OL} > 100 \mathrm{dB} \end{array}$		40	75 <b>75</b> 150	mV mV <b>mV</b> mV
	$\begin{array}{c c} R_{L} = 5k\Omega, A_{OL} > 96dB \\  V_{S} - V_{OUT}  < 1V \\ \text{sc} \end{array}$	See Ty	±10 ±40 pical Performar	150 nce Curves	mV mA mA
FREQUENCY RESPONSE Gain-Bandwidth Product GE	$\begin{array}{c c} C_{L} = 100 p F \\ G = +1 \\ V_{S} = \pm 5 V, \ G = +1 \\ V_{S} = \pm 5 V, \ 5 V \ Step, \ G = +1 \\ V_{S} = \pm 5 V, \ 5 V \ Step, \ G = +1 \\ V_{IN} \bullet \ Gain = V_{S} \end{array}$		1 0.6 15 20 3 0.02		MHz V/μs μs μs μs %
	$I_{\rm S}$ $I_{\rm Q}$ $I_{\rm O} = 0$	4 ±2	3.6 to 12 160	12 ±6 200 <b>300</b>	ν ν μΑ μ <b>Α</b>
SOT23-5 Surface-Mount MSOP-8 Surface-Mount TSSOP-14 Surface-Mount	aŭ	40 55 65	200 150 100	85 125 150	°C °C °C °C °C W °C/W
SO-8 Surface Mount SO-14 Surface Mount DIP-8			150 100 100		°C/W °C/W °C/W



# OPA704 ELECTRICAL CHARACTERISTICS: $V_S = 4V$ to 12V

### Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $+85^{\circ}C$

At T<sub>A</sub> = +25°C, R<sub>L</sub> = 20k\Omega connected to V<sub>S</sub>/2 and V<sub>OUT</sub> = V<sub>S</sub>/2, unless otherwise noted.

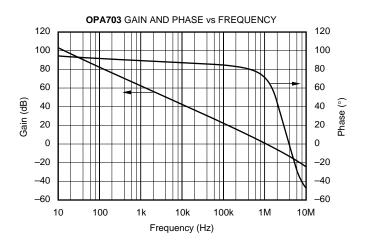
		OF	PA704NA, UA, PA2704EA, UA OPA4704EA, U	, PA	
PARAMETER	CONDITION	MIN	ТҮР	MAX	UNITS
OFFSET VOLTAGE         Input Offset Voltage $V_{02}$ Drift $dV_{03}/d1$ vs Power Supply       PSRF         Over Temperature       Channel Separation, dc         f = 1kHz       f = 1kHz	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		±160 ± <b>4</b> 20 1 98	±750 100 <b>200</b>	μV μ <b>V</b> /° <b>C</b> μV/V μ <b>V/V</b> μV/V dB
INPUT VOLTAGE RANGE Common-Mode Voltage Range Common-Mode Rejection Ratio over Temperature over Temperature		(V−) − 0.3 70 <b>68</b> 80 <b>74</b>	90 96	(V+) + 0.3	V dB dB dB
INPUT BIAS CURRENT Input Bias Current In Input Offset Current Inc	$V_{\rm S}=\pm5V, V_{\rm CM}=0V$		±1 ±0.5	±10 ±10	pA pA
INPUT IMPEDANCE Differential Common-Mode			4 • 10 <sup>9</sup>    4 5 • 10 <sup>12</sup>    4		Ω    pF Ω    pF
NOISE           Input Voltage Noise, f = 0.1Hz to 10Hz           Input Voltage Noise Density, f = 1kHz           Current Noise Density, f = 1kHz			6 45 2.5		μVp-p nV/√Hz fA/√Hz
OPEN-LOOP GAIN Open-Loop Voltage Gain A <sub>OI</sub> over Temperature over Temperature		100 <b>96</b> 100 <b>96</b>	120 110 110		dB dB dB dB
OUTPUT         Voltage Output Swing from Rail         over Temperature         over Temperature         Output Current         Short-Circuit Current         Capacitive Load Drive		See Ty	40 ±10 ±40 pical Performar	75 <b>75</b> 150 <b>150</b> nce Curves	mV mV mV mV mA mA
FREQUENCY RESPONSE         Gain-Bandwidth Product       GBW         Slew Rate       SF         Settling Time, 0.1%       tg         0.01%       0         Overload Recovery Time       ThD+N         Total Harmonic Distortion + Noise       THD+N	$\begin{array}{c} C_{L} = 100 p F \\ G = +5 \\ V_{S} = \pm 5 V, \ G = +5 \\ V_{S} = \pm 5 V, \ 5 V \ Step, \ G = +5 \\ V_{S} = \pm 5 V, \ 5 V \ Step, \ G = +5 \\ V_{IN} \bullet \ Gain = V_{S} \end{array}$		3 3 18 21 0.6 0.025		MHz V/μs μs μs μs %
POWER SUPPLY         Specified Voltage Range, Single Supply         Specified Voltage Range, Dual Supplies         Operating Voltage Range         Quiescent Current (per amplifier)         over Temperature		4 ±2	3.6 to 12 160	12 ±6 200 <b>300</b>	V V ν μΑ μ <b>Α</b>
TEMPERATURE RANGE         Specified Range         Operating Range         Storage Range         Thermal Resistance         ØJ         SOT23-5 Surface-Mount         MSOP-8 Surface-Mount         TSSOP-14 Surface-Mount         SO-8 Surface Mount         SO-14 Surface Mount         SO-14 Surface Mount         DIP-8		40 55 65	200 150 100 150 100 100	85 125 150	°C °C °C °C/W °C/W °C/W °C/W °C/W °C/W

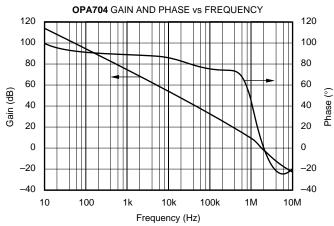


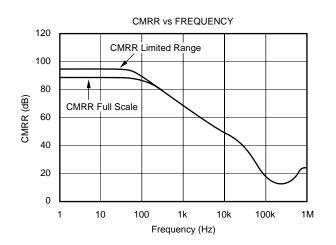


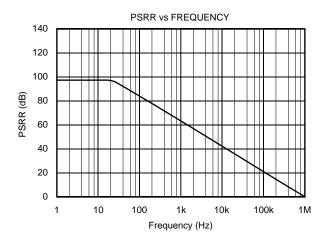
# **TYPICAL CHARACTERISTICS**

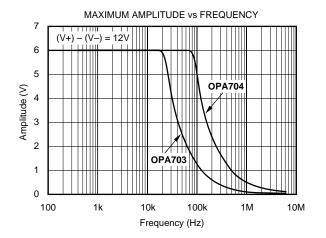
At  $T_{A}$  = +25°C,  $V_{S}$  =  $\pm 5V,$  and  $R_{L}$  = 20k $\Omega,$  unless otherwise noted.

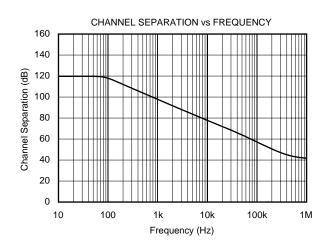








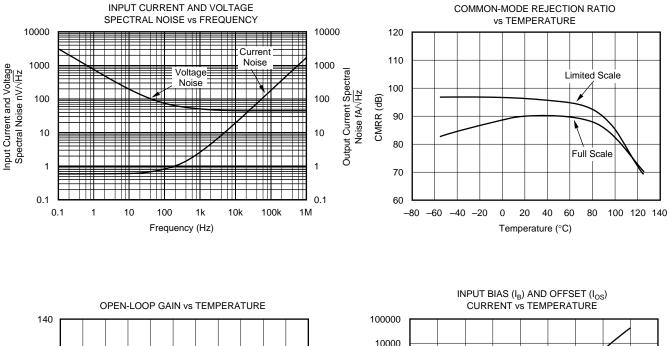




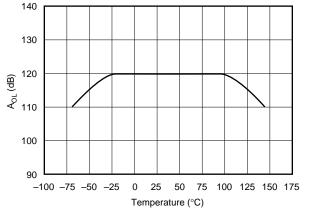


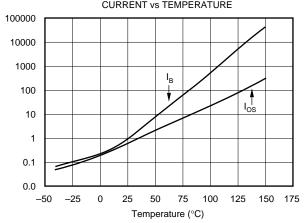


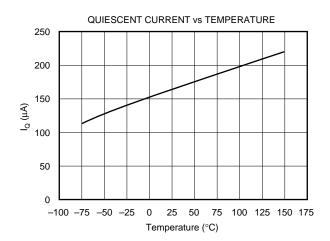
At T\_A = +25°C, V\_S =  $\pm$ 5V, and R<sub>L</sub> = 20k $\Omega$ , unless otherwise noted.

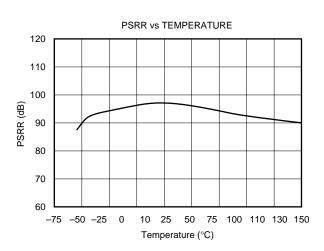


Bias Current (pA)





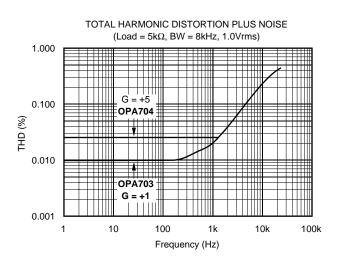








At  $T_A = +25^{\circ}C$ ,  $V_S = \pm 5V$ , and  $R_L = 20k\Omega$ , unless otherwise noted.



INPUT BIAS CURRENT (IB)

15

10

5

0

-5

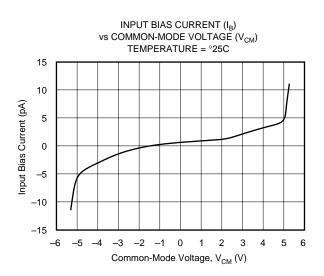
-10

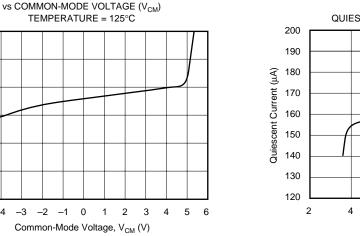
-15

-6

-5 -4 -3

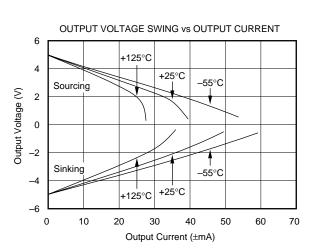
Input Bias Current (nA)





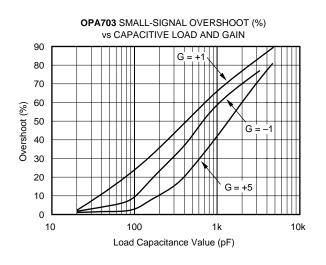
SHORT-CIRCUIT CURRENT vs SUPPLY VOLTAGE 60 I<sub>SC</sub> N (Sinking) 50 Short-Circuit Current (mA) 40 30 I<sub>SC</sub> P (Sourcing) 20 10 0 2 4 6 8 10 12 14 Supply Voltage (V)

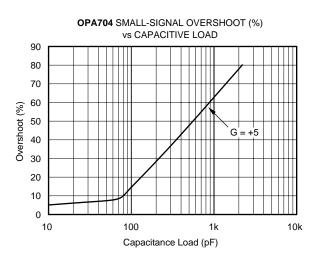
QUIESCENT CURRENT vs SUPPLY VOLTAGE 10 6 8 12 14 Supply Voltage (V)

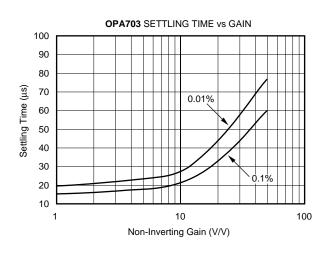


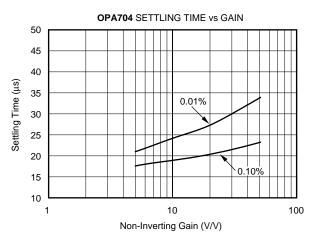


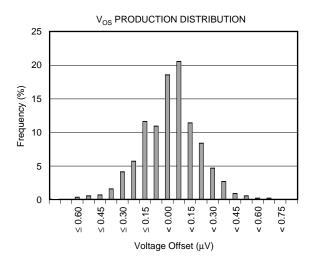
At  $T_{A}$  = +25°C,  $V_{S}$  =  $\pm 5V,$  and  $R_{L}$  = 20k $\Omega,$  unless otherwise noted.

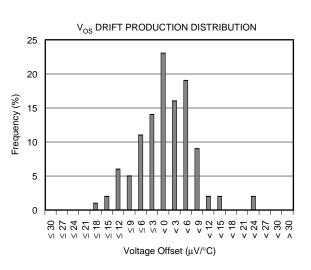








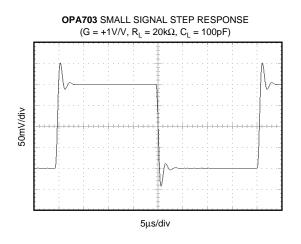


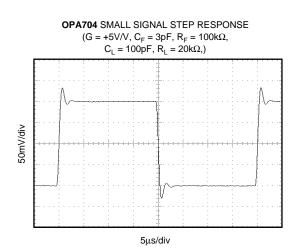




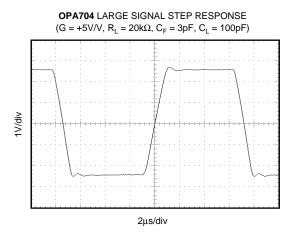


At  $T_{A}$  = +25°C,  $V_{S}$  =  $\pm 5V,$  and  $R_{L}$  = 20k $\Omega,$  unless otherwise noted.





OPA703 LARGE SIGNAL STEP RESPONSE $(G = +1V/V, R_L = 20k\Omega, C_L = 100pF)$ 







# APPLICATIONS INFORMATION

OPA703 and OPA704 series op amps can operate on  $160\mu$ A quiescent current from a single (or split) supply in the range of 4V to 12V ( $\pm 2V$  to  $\pm 6V$ ), making them highly versatile and easy to use. The OPA703 is unity-gain stable and offers 1MHz bandwidth and  $0.6V/\mu$ s slew rate. The OPA704 is optimized for gains of 5 or greater with a 3MHz bandwidth and  $3V/\mu$ s slew rate.

Rail-to-rail input and output swing helps maintain dynamic range, especially in low supply applications. Figure 1 shows the input and output waveforms for the OPA703 in unitygain configuration. Operation is from a  $\pm 5V$  supply with a 100k $\Omega$  load connected to  $V_S/2$ . The input is a 10Vp-p sinusoid. Output voltage is approximately 10Vp-p.

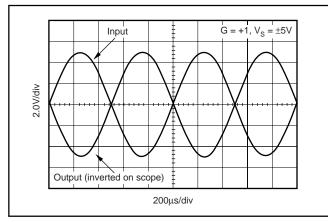


FIGURE 1. Rail-to-Rail Input and Output.

Power-supply pins should be bypassed with 1000pF ceramic capacitors in parallel with  $1\mu$ F tantalum capacitors.

#### OPERATING VOLTAGE

OPA703 and OPA704 series op amps are fully specified and guaranteed from +4V to +12V over a temperature range of -40°C to +85°C. Parameters that vary significantly with operating voltages or temperature are shown in the Typical Performance Curves.

#### RAIL-TO-RAIL INPUT

The input common-mode voltage range of the OPA703 series extends 300mV beyond the supply rails at room temperature. This is achieved with a complementary input stage-an Nchannel input differential pair in parallel with a P-channel differential pair, as shown in Figure 2. The N-channel pair is active for input voltages close to the positive rail, typically (V+) - 2.0V to 300mV above the positive supply, while the Pchannel pair is on for inputs from 300mV below the negative supply to approximately (V+) - 1.5V. There is a small transition region, typically (V+) - 2.0V to (V+) - 1.5V, in which both pairs are on. This 500mV transition region can vary ±100mV with process variation. Thus, the transition region (both stages on) can range from (V+) - 2.1V to (V+)-1.4V on the low end, up to (V+) -1.9V to (V+) -1.6V on the high end. Within the 500mV transition region PSRR, CMRR, offset voltage, and offset drift, and THD may vary compared to operation outside this region.

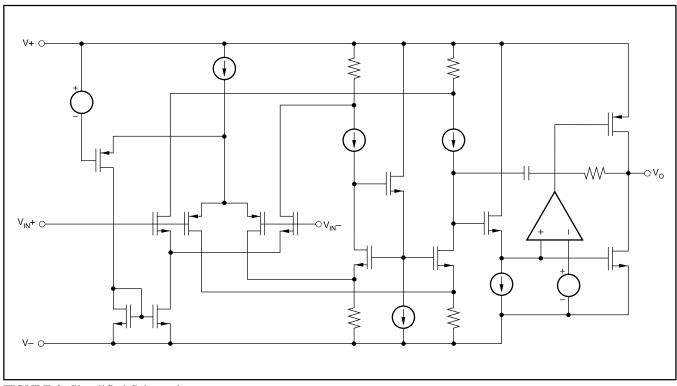


FIGURE 2. Simplified Schematic.



#### **INPUT VOLTAGE**

Device inputs are protected by ESD diodes that will conduct if the input voltages exceed the power supplies by more than approximately 300mV. Momentary voltages greater than 300mV beyond the power supply can be tolerated if the current is limited to 10mA. This is easily accomplished with an input resistor, as shown in Figure 3. Many input signals are inherently current-limited to less than 10mA; therefore, a limiting resistor is not always required. The OPA703 features no phase inversion when the inputs extend beyond supplies if the input current is limited, as seen in Figure 4.

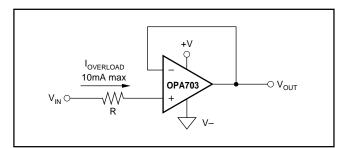


FIGURE 3. Input Current Protection for Voltages Exceeding the Supply Voltage.

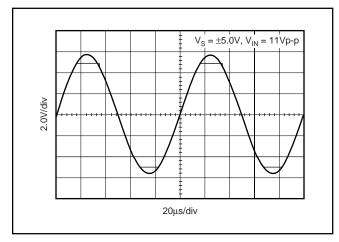


FIGURE 4. OPA703—No Phase Inversion with Inputs Greater than the Power-Supply Voltage.

#### **RAIL-TO-RAIL OUTPUT**

A class AB output stage with common-source transistors is used to achieve rail-to-rail output. This output stage is capable of driving  $1k\Omega$  loads connected to any point between V+ and ground. For light resistive loads (> 100k\Omega), the output voltage can swing to 40mV from the supply rail. With moderate resistive loads (20k $\Omega$ ), the output can swing to within 75mV from the supply rails while maintaining high open-loop gain (see the typical performance curve "Output Voltage Swing vs Output Current").

#### CAPACITIVE LOAD AND STABILITY

The OPA703 and OPA704 series op amps can drive up to 1000pF pure capacitive load. Increasing the gain enhances the amplifier's ability to drive greater capacitive loads (see the typical performance curve "Small Signal Overshoot vs Capacitive Load").

One method of improving capacitive load drive in the unitygain configuration is to insert a  $10\Omega$  to  $20\Omega$  resistor inside the feedback loop, as shown in Figure 5. This reduces ringing with large capacitive loads while maintaining DC accuracy.

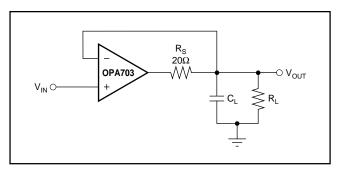


FIGURE 5. Series Resistor in Unity-Gain Buffer Configuration Improves Capacitive Load Drive.

#### **APPLICATION CIRCUITS**

Figure 6 shows a G = 5 non-inverting amplifier implemented with the OPA703 and OPA704 op amps. It demonstrates the increased speed characteristics (bandwidth, slew rate and settling time) that can be achieved with the OPA704 family when used in gains of five or greater. Some optimization of feedback capacitor value may be required to achieve best dynamic response. Circuits with closed-loop gains of less than five should use the OPA703 family for good stability and capacitive load drive. The OPA703 can be used in gains greater than five, but will not provide the increased speed benefits of the OPA704 family.

The OPA703 series op amps are optimized for driving medium-speed sampling data converters. The OPA703 op amps buffer the converter's input capacitance and resulting charge injection while providing signal gain.

Figure 7 shows the OPA2703 in a dual-supply buffered reference configuration for the DAC7644. The DAC7644 is a 16-bit, low-power, quad-voltage output converter. Small size makes the combination ideal for automatic test equipment, data acquisition systems, and other low-power space-limited applications.





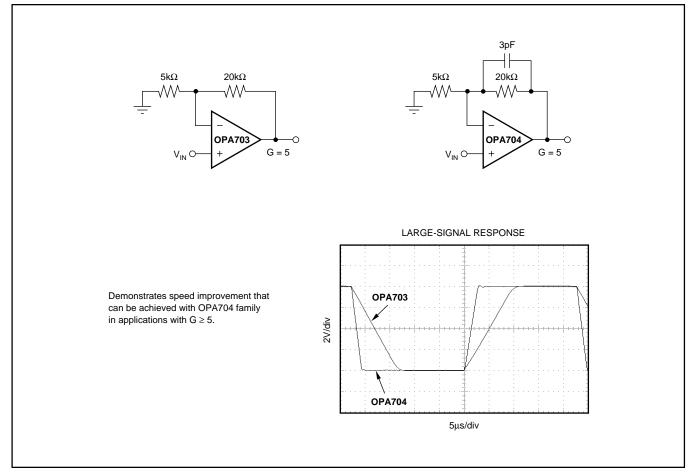


FIGURE 6. OPA704 Provides higher Speed in  $G \ge 5$ .

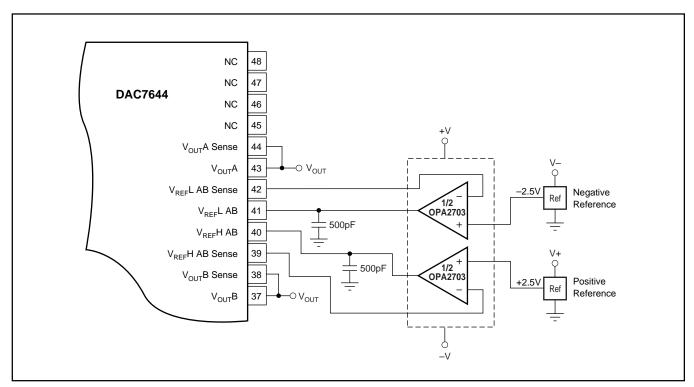


FIGURE 7. OPA703 as Dual Supply Configuration-Buffered References for the DAC7644.







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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OPA2703EA/250	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	B03	Samples
OPA2703EA/250G4	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	B03	Samples
OPA2703EA/2K5	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	B03	Samples
OPA2703EA/2K5G4	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	B03	Samples
OPA2703UA	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2703UA	Samples
OPA2703UA/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2703UA	Samples
OPA2703UA/2K5G4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2703UA	Samples
OPA2704EA/250	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	B04	Samples
OPA2704EA/250G4	ACTIVE	VSSOP	DGK	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 85	B04	Samples
OPA2704UA	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2704UA	Samples
OPA2704UA/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2704UA	Samples
OPA2704UA/2K5G4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 2704UA	Samples
OPA4703EA/250	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 4703EA	Samples
OPA4703EA/250G4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 4703EA	Samples
OPA4703EA/2K5	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 4703EA	Samples
OPA4703EA/2K5G4	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 4703EA	Samples
OPA4703UA	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA4703UA	Samples



### PACKAGE OPTION ADDENDUM

26-Feb-2019

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
OPA4703UAG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA4703UA	Samples
OPA4704EA/250	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 4704EA	Samples
DPA4704EA/250G4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 4704EA	Samples
OPA4704EA/2K5	ACTIVE	TSSOP	PW	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 4704EA	Samples
OPA4704UA	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA4704UA	Samples
OPA703NA/250	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A03	Samples
OPA703NA/250G4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A03	Samples
OPA703NA/3K	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A03	Samples
OPA703NA/3KG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A03	Samples
OPA703PA	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type	-40 to 85	OPA703PA	Samples
OPA703UA	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 703UA	Samples
OPA703UA/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 703UA	Samples
OPA704NA/250	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A04	Samples
OPA704NA/250G4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A04	Samples
OPA704NA/3K	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A04	Samples
OPA704NA/3KG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	A04	Samples
OPA704UA	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 704UA	Samples
OPA704UA/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	OPA 704UA	Samples



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(1) The marketing status values are defined as follows:
 ACTIVE: Product device recommended for new designs.
 LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
 NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
 PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
 OBSOLETE: TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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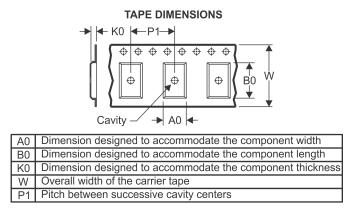
## PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2703EA/250	VSSOP	DGK	8	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2703EA/2K5	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2703UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2704EA/250	VSSOP	DGK	8	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2704UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA4703EA/250	TSSOP	PW	14	250	180.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
OPA4703EA/2K5	TSSOP	PW	14	2500	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
OPA4704EA/250	TSSOP	PW	14	250	180.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
OPA4704EA/2K5	TSSOP	PW	14	2500	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
OPA703NA/250	SOT-23	DBV	5	250	178.0	8.4	3.3	3.2	1.4	4.0	8.0	Q3
OPA703NA/3K	SOT-23	DBV	5	3000	178.0	8.4	3.3	3.2	1.4	4.0	8.0	Q3
OPA703UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA704NA/250	SOT-23	DBV	5	250	178.0	8.4	3.3	3.2	1.4	4.0	8.0	Q3
OPA704NA/3K	SOT-23	DBV	5	3000	178.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
OPA704UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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## PACKAGE MATERIALS INFORMATION

2-Sep-2015



All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2703EA/250	VSSOP	DGK	8	250	210.0	185.0	35.0
OPA2703EA/2K5	VSSOP	DGK	8	2500	367.0	367.0	35.0
OPA2703UA/2K5	SOIC	D	8	2500	367.0	367.0	35.0
OPA2704EA/250	VSSOP	DGK	8	250	210.0	185.0	35.0
OPA2704UA/2K5	SOIC	D	8	2500	367.0	367.0	35.0
OPA4703EA/250	TSSOP	PW	14	250	210.0	185.0	35.0
OPA4703EA/2K5	TSSOP	PW	14	2500	367.0	367.0	35.0
OPA4704EA/250	TSSOP	PW	14	250	210.0	185.0	35.0
OPA4704EA/2K5	TSSOP	PW	14	2500	367.0	367.0	35.0
OPA703NA/250	SOT-23	DBV	5	250	565.0	140.0	75.0
OPA703NA/3K	SOT-23	DBV	5	3000	565.0	140.0	75.0
OPA703UA/2K5	SOIC	D	8	2500	367.0	367.0	35.0
OPA704NA/250	SOT-23	DBV	5	250	565.0	140.0	75.0
OPA704NA/3K	SOT-23	DBV	5	3000	565.0	140.0	75.0
OPA704UA/2K5	SOIC	D	8	2500	367.0	367.0	35.0

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
   E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## D0008A



## **PACKAGE OUTLINE**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



## D0008A

## **EXAMPLE BOARD LAYOUT**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### D0008A

## **EXAMPLE STENCIL DESIGN**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



## **DBV0005A**



## **PACKAGE OUTLINE**

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.



## DBV0005A

## **EXAMPLE BOARD LAYOUT**

### SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## DBV0005A

## **EXAMPLE STENCIL DESIGN**

### SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.

- D Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



## DGK (S-PDSO-G8)

### PLASTIC SMALL OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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